

Low power, low offset voltage quad comparator in bare die form

Rev 1.0 04/05/18

Description

LM139 consists of x4 independent precision voltage comparators, each with low offset voltages of 2mV typical. The device operates on single or split power supply over a wide voltage range. Common mode input voltage range includes ground even in single supply operation. Supply current drain is independent of supply voltage, useful for low power applications. This device directly interfaces CMOS, TTL & MOS with split supply. Typical uses include level detection, low–level sensing, A/D conversion, VCOs, MOS clock generators, high voltage logic gates & multivibrators.

Ordering Information

The following part suffixes apply:

- No suffix MIL-STD-883 /2010B Visual Inspection
- "H" MIL-STD-883 /2010B Visual Inspection+ MIL-PRF-38534 Class H LAT
- "K" MIL-STD-883 /2010A Visual Inspection (Space)
 + MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

www.siliconsupplies.com\quality\bare-die-lot-qualification

For a higher electrical grade version of this product see LM139A

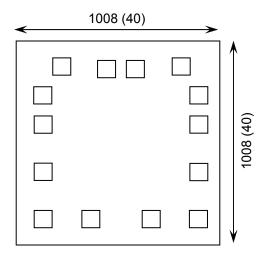
Supply Formats:

- Default Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape On request
- Unsawn Wafer On request
- Die Thickness <> 280µm(11 Mils) On request
- Assembled into Ceramic Package On request

Features:

- Single-Supply range: 2-36V
- Split–Supply range: ±1.0V to ±18V
- Low Input Offset Voltage 2mV typical
- Common mode input voltage includes ground
- Very low supply current independent of supply voltage (1 mW/comparator at +5V)
- Very Low Input Offset Current
- TTL, DTL, ECL, MOS, CMOS compatible outputs

Die Dimensions in µm (mils)



Mechanical Specification

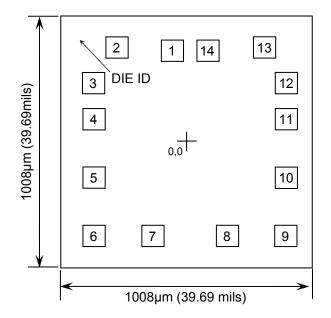
Die Size (Unsawn)	1008 x 1008 40 x 40	µm mils	
Minimum Bond Pad Size	94 x 94 3.7 x 3.7	μm mils	
Die Thickness	280 (±10) 11.02 (±0.39)	μm mils	
Top Metal Composition	Al 1%Si 1.1μm		
Back Metal Composition	N/A – Bare Si		





Rev 1.0 04/05/18

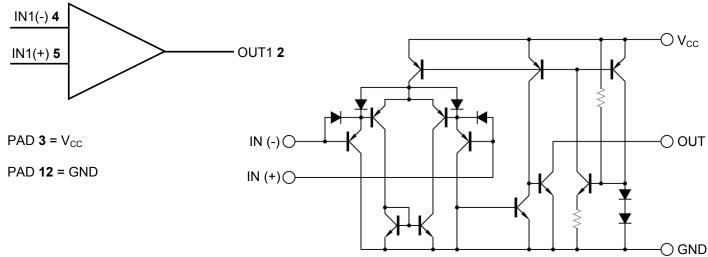
Pad Layout and Functions



PAD	FUNCTION	COORDINATES (µm)			
IAD	1 011011011	X	Υ		
1	OUTPUT 2	-57	391		
2	OUTPUT 1	-299	405		
3	V _{CC}	-398.5	251		
4	-INPUT 1	-396.5	97		
5	+INPUT 1	-396.5	-155		
6	-INPUT 2	-395	-405		
7	+INPUT 2	-143	-405		
8	-INPUT 3 179.5		-405		
9	+INPUT 3	431.5	-405		
10	-INPUT 4	433	-155		
11	+INPUT 4	433	97		
12	GND	435	251		
13	OUTPUT 4	339.5	405		
14	OUTPUT 3	97	391		
CHIP BACK POTENTIAL IS GND OR FLOAT					

Logic Diagram (Single channel)

Schematic (Single channel)







Rev 1.0 04/05/18

Absolute Maximum Ratings¹

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage – Single Supply	V _{cc}	36	V
Supply Voltage – Split Supply	▼ CC	±18	V
Input Differential Voltage Range	V_{IDR}	36	V
Input Common Mode Voltage Range	V_{ICR}	-0.3 to V _{CC}	V
Output Short Circuit to Ground	-	Continuous	-
Input Current (per pad) ²	I _{IN}	50	mA
Junction Temperature	T_{J}	150	°C
Power Dissipation in Still Air ³	P_D	756	mW

^{1.} Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability.

Recommended Operating Conditions

PARAMETER	SYMBOL	MIN	MAX	UNITS
DC Supply Voltage	V _{CC}	2	30	V
Operating Temperature	T _A	-55	+125	°C

DC Electrical Characteristics (V_{CC} =5V, T_A = 25°C unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS	LIMITS			UNITS	
PARAIVIETER	STIVIDOL	CONDITIONS		MIN	TYP	MAX	UNITS
Input Offset Voltage	V _{IO}	$V_{O} = 1.4V, R_{S} = 0\Omega;$ $V_{CC} = 5-30V,$	25°C	-	2	5	mV
input Onset Voltage	V IO	$V_{ICR} = 0V - (V_{CC} - 1.5V)$	125°C	-	-	9	IIIV
		$V_{O} = 1.4V, R_{S} = 0\Omega;$	25°C	-	25	100	_
Input Bias Current	l _B	$V_{CC} = 5-30V,$ $V_{ICR} = 0V-(V_{CC}-1.5V)$	125°C	-	-	300	nA
		$V_{O} = 1.4 V, R_{S} = 0 \Omega;$	25°C	-	3	25	
Input Offset Current	I_{IO} $V_{CC} = 5-30V,$ $V_{ICR} = 0V-(V_{CC}-1.5V)$	125°C	-	-	100	nA	
Input Common Mode	V	\/ - 5 20\/	25°C	0	-	V _{CC} -1.5	V
Voltage Range	V _{ICR}	$V_{CC} = 5-30V$	125°C	0	-	V _{CC} - 2.0	V
Supply Current		$R_{L}=\infty, V_{CC}=5V$ $R_{L}=\infty, V_{CC}=36V$		-	1.1	2	mΛ
Supply Current	I _{CC}			-	-	2.5	mA mA
Voltage Gain	A _{VOL}	$V_{CC} = 15V, R_L \ge 15$ $T_A = 25^{\circ}C, V_O = 1V t$	50	200	-	V/mV	
Large Signal Response Time	t ₁	V_{IN} =TTL Logic Swing, V_{REF} =1.4V, V_{RL} = 5V R_{L} = 5.1K Ω		-	300	-	ns
Response Time	t ₂	$R_L = 5.1 K\Omega$, $V_{RL} = 5V$		-	1.3	-	μS



^{2.} V_{IN} < -0.3V. This input current exists when voltage is driven negative at any of the input leads

^{3.} Assembled in 14 lead PDIP



Rev 1.0 04/05/18

DC Electrical Characteristics (V_{CC} =5V, T_A = 25°C unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS			LIMITS		UNITS	
FANAMETER	STWIDOL			MIN	TYP	MAX	ONITS	
Output Sink Current	I _{SINK}	$V_{I}(-) = 1V, V_{I}(+) = 0V,$ $V_{O} \le 1.5V$		6	18	-	mA	
Caturation Valtage	\	$V_{I}(-) = 1V, V_{I}(+) = 0V$ 25°C $I_{SINK} \le 4mA$ 125°C		25°C	-	140	400	m\/
Saturation Voltage	V _{SAT}			125°C	-	-	700	- mV
Output Leakage	I _{OL}			5V, 25°C	-	0.1	-	nA
Current	OL	V _I (-) = 0V	$V_{O} = 30V,$ $T_{A} = 125^{\circ}C$		-	-	1000	
Differential Input Voltage Range	V _{IDR}	All V _{IN} ≥ GND or V- Supply (if used)		-	-	V _{CC}	V	

Typical Characteristics

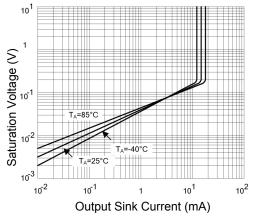


FIGURE 1. Output Saturation Voltage vs Output Sink Current

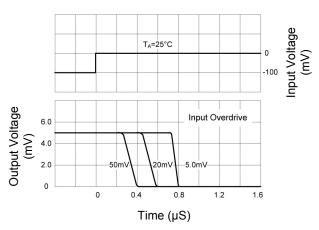


FIGURE 2. Input Overdrive Response time

- Negative transition

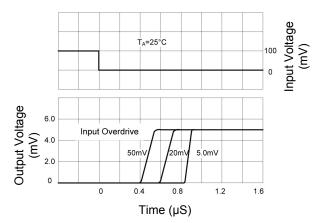


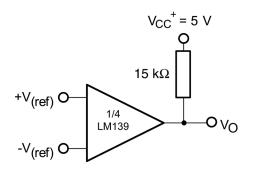
FIGURE 3. Input Overdrive Response time
- Positive transition





Rev 1.0 04/05/18

Typical Applications



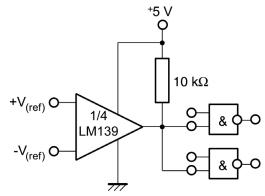


FIGURE 4. Basic Comparator

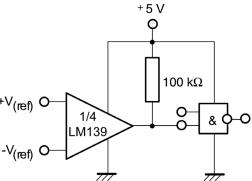
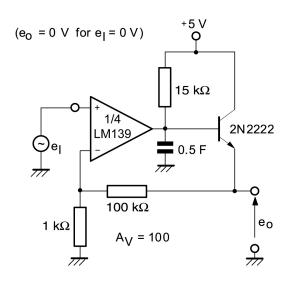


FIGURE 5. Driving TTL

FIGURE 6. Driving CMOS



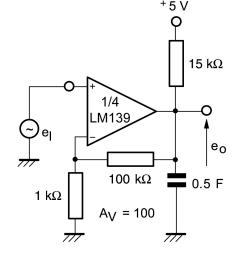


FIGURE 7. Low frequency Operational Amplifier V1

FIGURE 8. Low frequency Operational Amplifier V2





Rev 1.0 04/05/18

Typical Applications continued

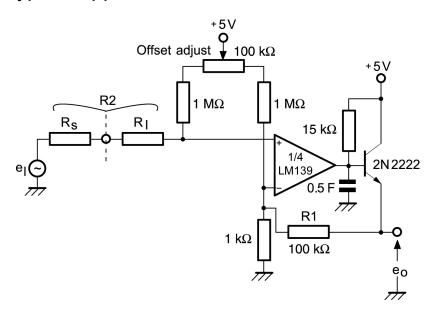


FIGURE 9. Low frequency Op-Amp with Offset adjust

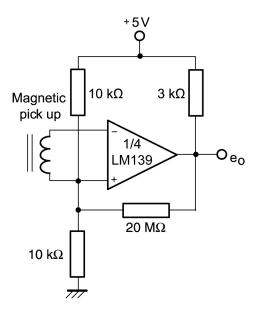


FIGURE 10. Transducer Amplifier

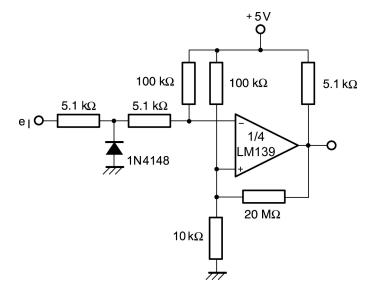


FIGURE 11. Zero crossing detector (single power supply)

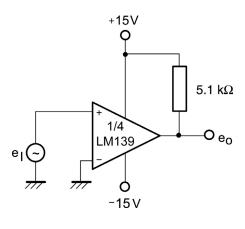


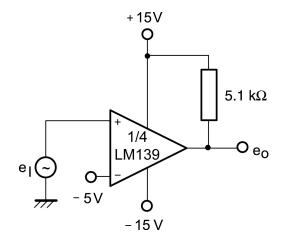
FIGURE 12. Zero crossing detector (split power supply)





Rev 1.0 04/05/18

Typical Applications continued



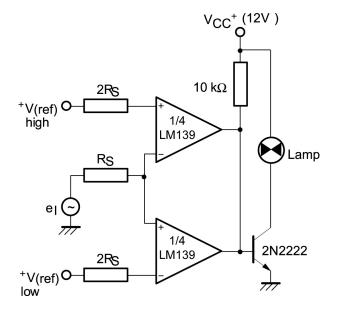


FIGURE 13. Comparator with a negative reference

FIGURE 14. Limit Comparator

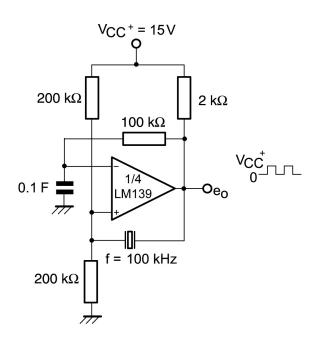


FIGURE 15. Crystal controlled Comparator





Rev 1.0 04/05/18

Typical Applications continued

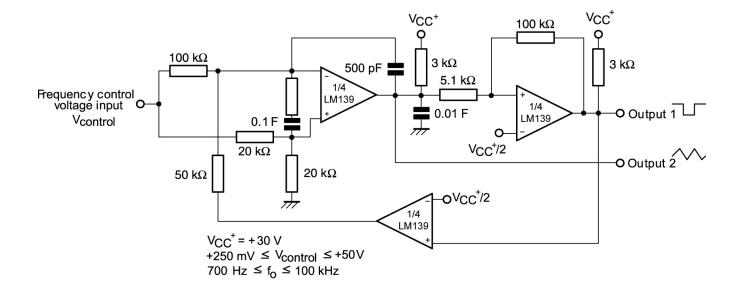


FIGURE 16. Two-decade High-Frequency VCO

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